

PMN70EPE 30 V, P-channel Trench MOSFET

Product data sheet

1. General description

P-channel enhancement mode Field-Effect Transistor (FET) in a small SOT457 (SC-74) Surface-Mounted Device (SMD) plastic package using Trench MOSFET technology.

2. Features and benefits

- Trench MOSFET technology
- Logic-level compatible
- Very fast switching

23 May 2017

- Enhanced power dissipation capability of 1.4 W
- ElectroStatic Discharge (ESD) protection > 2 kV HBM

3. Applications

- Relay driver
- High-speed line driver
- High-side loadswitch
- Switching circuits

4. Quick reference data

Table 1. Qui	ck reference data						
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V _{DS}	drain-source voltage	T _j = 25 °C		-	-	-30	V
V _{GS}	gate-source voltage			-20	-	20	V
I _D	drain current	V_{GS} = -10 V; T_{amb} = 25 °C; t ≤ 5 s	[1]	-	-	-4.4	А
Static chara	acteristics						
R _{DSon}	drain-source on-state resistance	V_{GS} = -10 V; I _D = -3.3 A; T _j = 25 °C		-	60	80	mΩ

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated, mounting pad for drain 6 cm².



5. Pinning information

Table 2. Pinning information							
Pin	Symbol	Description	Simplified outline	Graphic symbol			
1	D	drain		D			
2	D	drain					
3	G	gate		G ↓ ↓ ↓ ↓			
4	S	source	TSOP6 (SOT457)				
5	D	drain					
6	D	drain		I S			
				017aaa259			

6. Ordering information

Table 3. Ordering information						
Type number	Package					
	Name	Description	Version			
PMN70EPE	TSOP6	plastic surface-mounted package (TSOP6); 6 leads	SOT457			

7. Marking

Table 4. Marking codes	
Type number	Marking code
PMN70EPE	G2

8. Limiting values

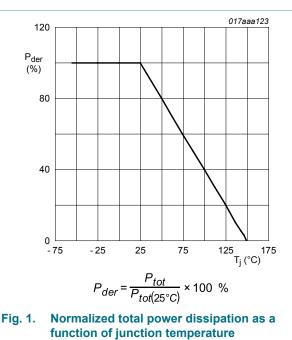
Table 5. Limiting values

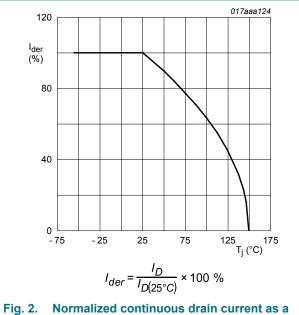
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Мах	Unit
V _{DS}	drain-source voltage	T _j = 25 °C		-	-30	V
V _{GS}	gate-source voltage			-20	20	V
I _D	drain current	V _{GS} = -10 V; T _{amb} = 25 °C; t ≤ 5 s	[1]	-	-4.4	А
		V _{GS} = -10 V; T _{amb} = 25 °C	[1]	-	-3.3	А
		V _{GS} = -10 V; T _{amb} = 100 °C	[1]	-	-2.1	А
I _{DM}	peak drain current	T_{amb} = 25 °C; single pulse; $t_p \le 10 \ \mu s$		-	-14	А
P _{tot}	total power dissipation	T _{amb} = 25 °C	[2]	-	570	mW
			[1]	-	1.4	W
		T _{sp} = 25 °C		-	6.25	W
Tj	junction temperature			-55	150	°C
T _{amb}	ambient temperature			-55	150	°C
T _{stg}	storage temperature			-65	150	°C
Source-drai	n diode					
I _S	source current	T _{amb} = 25 °C	[1]	-	-1.4	А

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated, mounting pad for drain 6 cm².

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

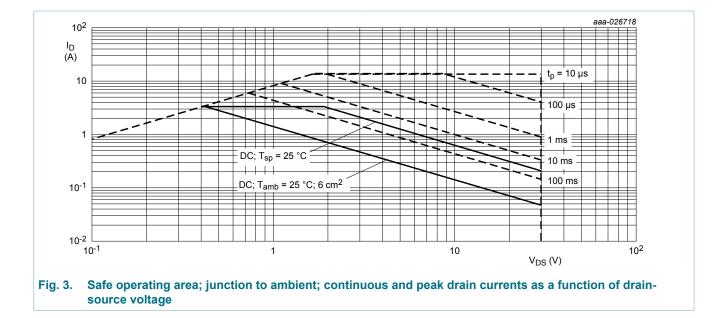






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9. Thermal characteristics

Table 6. Thermal characteristics

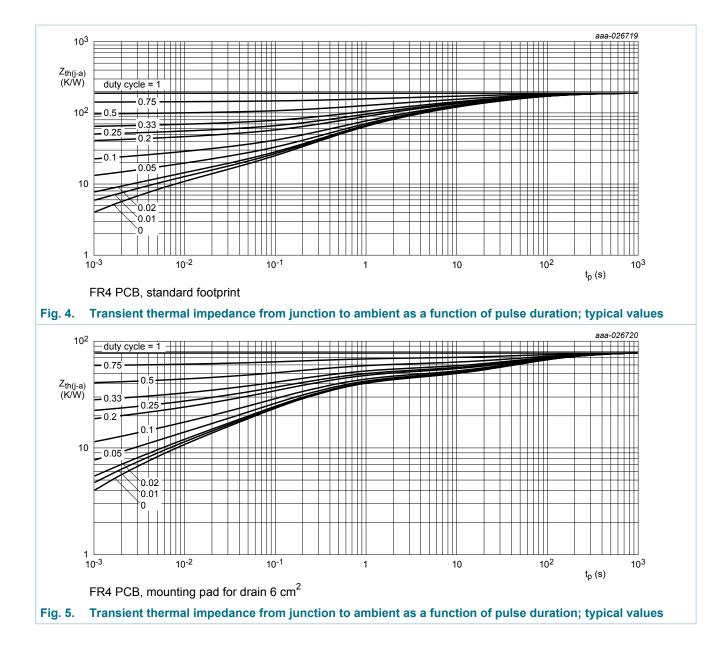
	ui chui ucteri stics						
Symbol	Parameter	Conditions		Min	Тур	Мах	Unit
R _{th(j-a)}	thermal resistance from junction to ambient	-	[1]	-	190	220	K/W
			[2]	-	78	90	K/W
		in free air; t ≤ 5 s	[2]	-	47	54	K/W
R _{th(j-sp)}	thermal resistance from junction to solder point			-	15	20	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for drain 6 cm².

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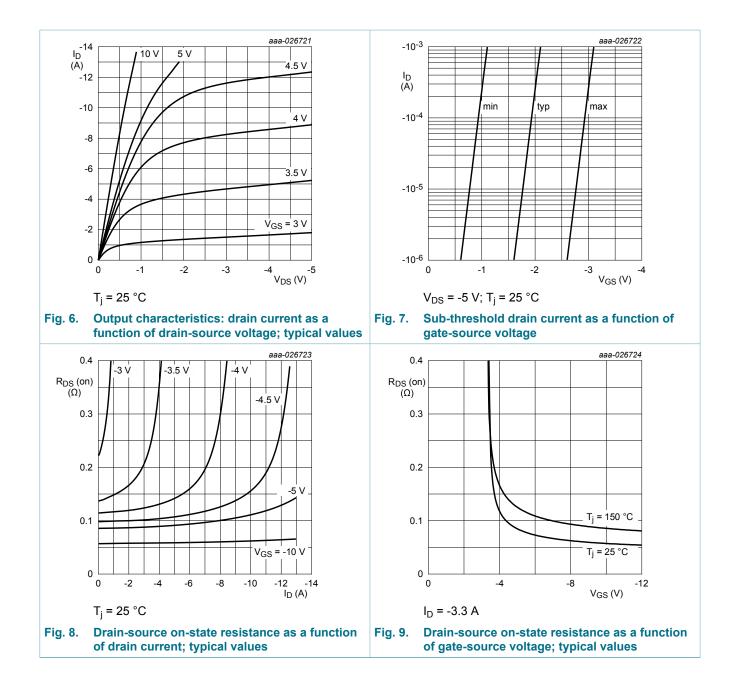


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10. Characteristics

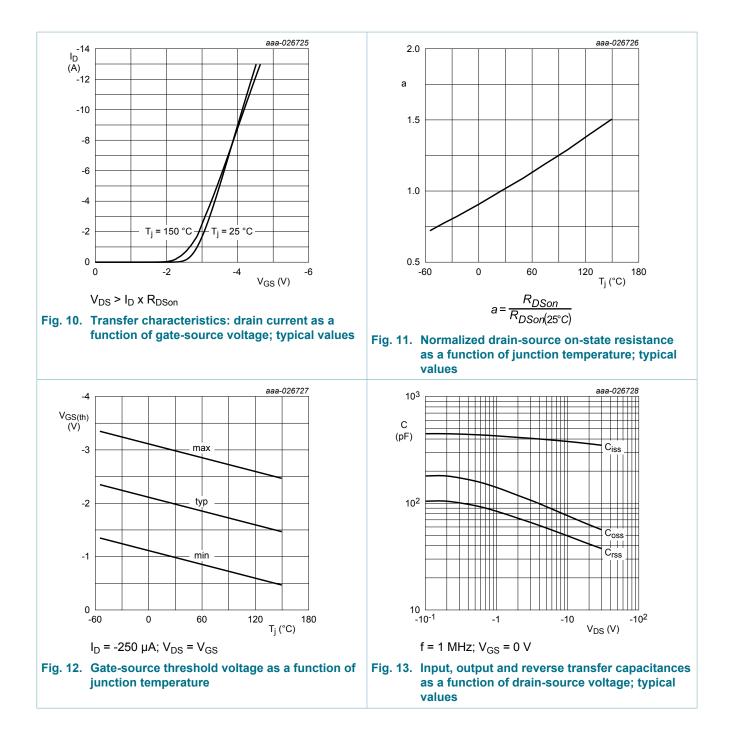
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	octeristics					
V _{(BR)DSS}	drain-source breakdown voltage	I_D = -250 µA; V_{GS} = 0 V; T_j = 25 °C	-30	-	-	V
V _{GSth}	gate-source threshold voltage	I_D = -250 µA; V_{DS} = V_{GS} ; T_j = 25 °C	-1	-2	-3	V
I _{DSS}	drain leakage current	V_{DS} = -30 V; V_{GS} = 0 V; T_j = 25 °C	-	-	-1	μA
I _{GSS}	gate leakage current	V_{GS} = 20 V; V_{DS} = 0 V; T_j = 25 °C	-	-	10	μA
		V_{GS} = -20 V; V_{DS} = 0 V; T_j = 25 °C	-	-	-10	μA
		V _{GS} = 10 V; V _{DS} = 0 V; T _j = 25 °C	-	-	1	μA
		V_{GS} = -10 V; V_{DS} = 0 V; T_j = 25 °C	-	-	-1	μA
		V_{GS} = 4.5 V; V_{DS} = 0 V; T_j = 25 °C	-	-	100	nA
		V_{GS} = -4.5 V; V_{DS} = 0 V; T_j = 25 °C	-	-	-100	nA
R _{DSon}	P _{DSon} drain-source on-state resistance	V _{GS} = -10 V; I _D = -3.3 A; T _j = 25 °C	-	60	80	mΩ
resi		V _{GS} = -10 V; I _D = -3.3 A; T _j = 150 °C	-	91	121	mΩ
		V _{GS} = -4.5 V; I _D = -2.6 A; T _j = 25 °C	-	96	140	mΩ
9 _{fs}	forward transconductance	V_{DS} = -10 V; I _D = -2 A; T _j = 25 °C	-	12.6	-	S
R _G	gate resistance	f = 1 MHz; T _j = 25 °C	-	12	-	Ω
Dynamic ch	aracteristics	· · ·				
Q _{G(tot)}	total gate charge	V_{DS} = -15 V; I_D = -3.3 A; V_{GS} = -10 V;	-	6.5	11.5	nC
Q _{GS}	gate-source charge	T _j = 25 °C	-	1.2	-	nC
Q _{GD}	gate-drain charge		-	1.2	-	nC
C _{iss}	input capacitance	$V_{DS} = -15 \text{ V}; \text{ f} = 1 \text{ MHz}; V_{GS} = 0 \text{ V};$	-	370	-	pF
C _{oss}	output capacitance	T _j = 25 °C	-	64	-	pF
C _{rss}	reverse transfer capacitance		-	44	-	pF
t _{d(on)}	turn-on delay time	V_{DS} = -15 V; I _D = -3.3 A; V _{GS} = -10 V;	-	5	-	ns
t _r	rise time	$R_{G(ext)} = 6 \Omega; T_j = 25 °C$	-	8	-	ns
t _{d(off)}	turn-off delay time		-	19	-	ns
t _f	fall time		-	7.5	-	ns
Source-drai	n diode	· · ·				
V _{SD}	source-drain voltage	I _S = -1.4 A; V _{GS} = 0 V; T _i = 25 °C	-	-0.8	-1.2	V

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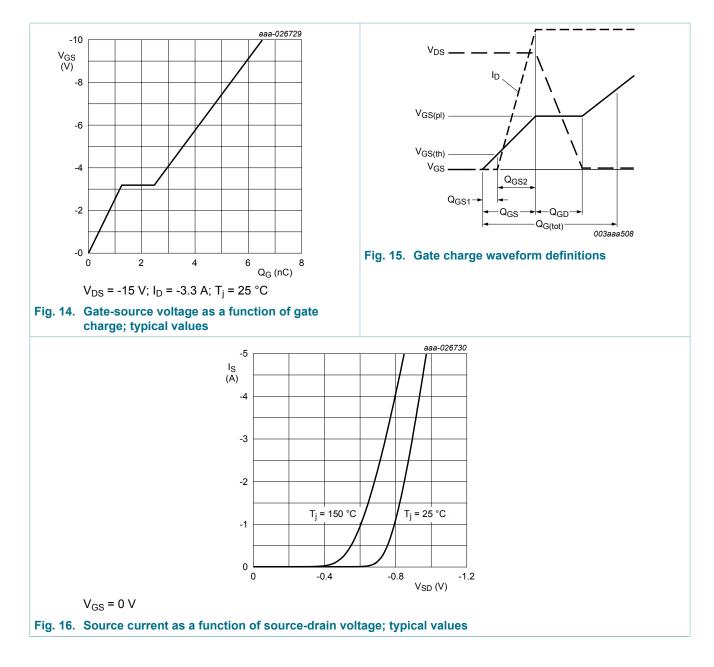
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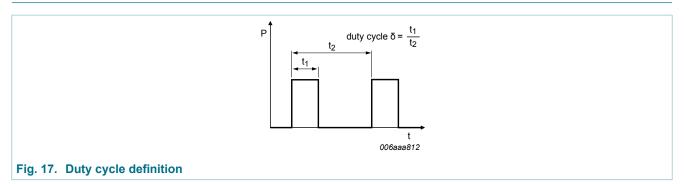


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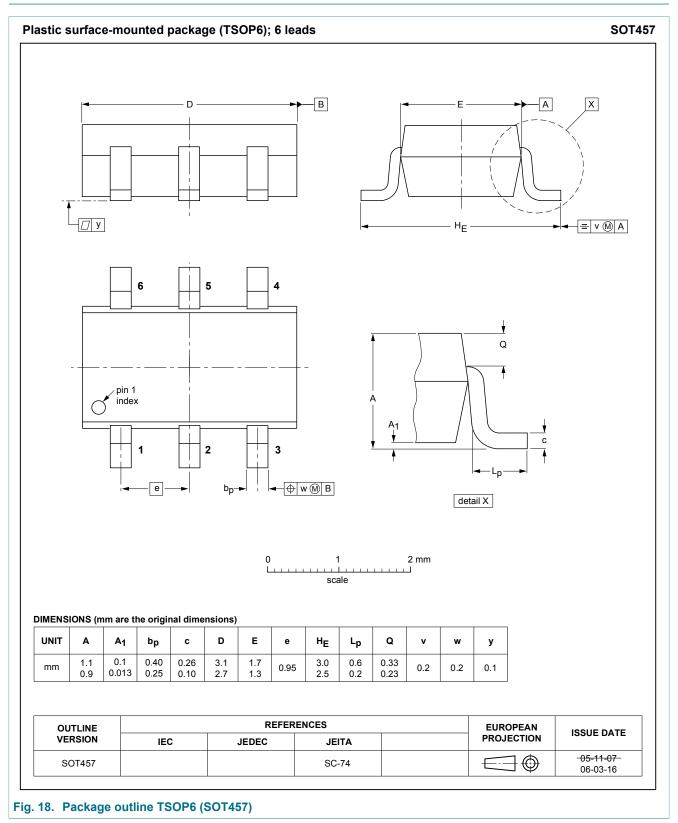
11. Test information



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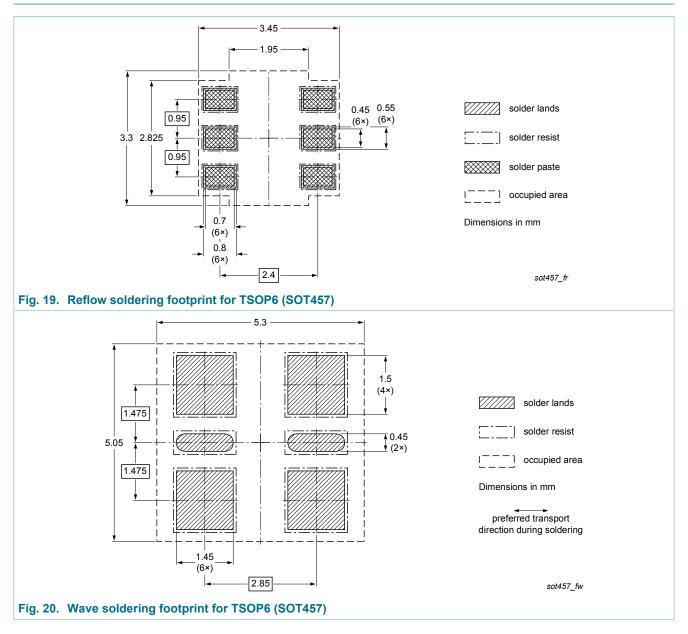
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12. Package outline



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13. Soldering



14. Revision history

Table 8. Revision history						
Data sheet ID	Release date	Data sheet status	Change notice	Supersedes		
PMN70EPE v.1	20170523	Product data sheet	-	-		

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15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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